



REVISION HISTORY

Revision	Description	Issue Date
1.0	Initial issue	Feb 2007
2.0	Add-in industrial temperature option for 28-pin 600 mil PDIP.	July 2017
	Standby current(Isb1) reduced to be 20uA for	
	I-grade and 10uA for C grade	

FEATURES

- Access time :55ns
- Low power consumption: Operation current :

15mA (TYP.), Vcc = 3.0V

Standby current:

 $1\mu A (TYP.), V_{CC} = 3.0V$

- Wide range power supply : 2.7 ~ 5.5V
- Fully Compatible with all Competitors 5V product
- Fully Compatible with all Competitors 3.3V product
- All inputs and outputs TTL compatible
- Fully static operation
- Tri-state output
- Data retention voltage :1.5V (MIN.)
- All products ROHS Compliant
- Package : 28-pin 600 mil PDIP 28-pin 330 mil SOP

28-pin 8mm x 13.4mm sTSOP

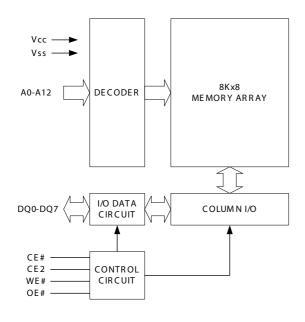
GENERAL DESCRIPTION

The AS6C6264 is a 65,536-bit low power CMOS static random access memory organized as 8,192 words by 8 bits. It is fabricated using very high performance, high reliability CMOS technology. Its standby current is stable within the range of operating temperature.

The AS6C6264 is well designed for low power application, and particularly well suited for battery back-up nonvolatile memory application.

The AS6C6264 operates with wide range power supply.

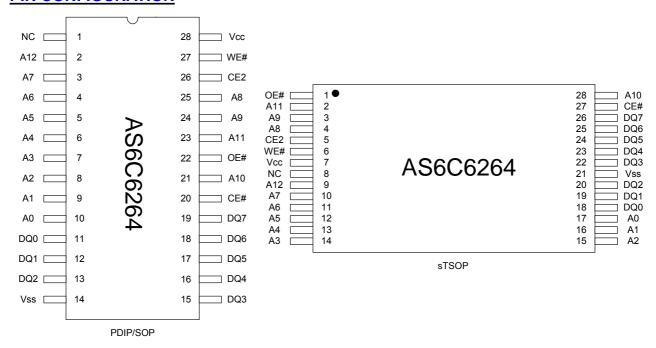
FUNCTIONAL BLOCK DIAGRAM



PIN DESCRIPTION

SYMBOL	DESCRIPTION
A0 - A12	Address Inputs
DQ0 – DQ7	Data Inputs/Outputs
CE#, CE2	Chip Enable Inputs
WE#	Write Enable Input
OE#	Output Enable Input
Vcc	Power Supply
Vss	Ground
NC	No Connection

PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS*

PARAMETER	SYMBOL	RATING	UNIT
Terminal Voltage with Respect to Vss	VTERM	-0.5 to 7.0	V
		0 to 70(C grade)	
Operating Temperature	TA		°C
		-40 to 85(I grade)	
Storage Temperature	Тѕтс	-65 to 150	°C
Power Dissipation	PD	1	W
DC Output Current	Іоит	50	mA
Soldering Temperature (under 10 sec)	Tsolder	260	°C

^{*}Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

TRUTH TABLE

MODE	CE#	CE2	OE#	WE#	I/O OPERATION	SUPPLY CURRENT
Standby	Н	Х	Х	Х	High-Z	ISB,ISB1
Startuby	Х	L	Х	Х	High-Z	ISB,ISB1
Output Disable	L	Н	Н	Н	High-Z	Icc,Icc1
Read	L	Н	L	Н	Dout	Icc,Icc1
Write	L	Н	Х	L	Din	lcc,lcc1

Note: H = V_{IH}, L = V_{IL}, X = Don't care.



DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDIT	ION	MIN.	TYP. *5	MAX.	UNIT
Supply Voltage	Vcc			2.7	3.0	5.5	V
Input High Voltage	V _{IH} *1			2.4V	-	Vcc+0.3	V
Input Low Voltage	V _{IL} ²			- 0.5	-	0.6	V
Input Leakage Current	ILI	Vcc ≥ Vin ≥ Vss		- 1	-	1	μA
Output Leakage Current	ILO	Vcc ≧ Vouт ≧ Vss, Output Disabled		- 1	-	1	μA
Output High Voltage	Vон	I _{OH} = -1mA		2.4	3.0	-	V
Output Low Voltage	Vol	I _{OL} = 2mA		-	-	0.4	V
Average Operating	lcc	Cycle time = Min. CE# = V_{IL} and CE2 = $I_{I/O}$ = 0mA	V _{IH} , - 55	-	15	45	mA
Average Operating Power supply Current	Icc1	Cycle time = 1µs CE#≦0.2V and CE2≩ II/o = 0mA other pins at 0.2V or \		-	3	10	mA
Standby Power	lon4	CE# ≧ Vcc-0.2V	-C		1	10 *4	μA
Supply Current	I _{SB1}	or CE2≦0.2V	-	-	1	20*4	μA

Notes: C = Commercial Temperature I = Industrial temperature

- 1. V_{IH}(max) =V_{CC} + 3.0V for pulse width less than 10ns.
- 2. V_{IL}(min) =V_{SS} 3.0V for pulse width less than 10ns.
- 3. Over/Undershoot specifications are characterized, not 100% tested.
- 4. $10\,\mu\text{A}$ for special request
- 5. Typical values are included for reference only and are not guaranteed or tested. Typical valued are measured at Vcc = Vcc(TYP.) and T_A = 25°C

CAPACITANCE ($T_A = 25^{\circ}C$, f = 1.0MHz)

PARAMETER	SYMBOL	MIN.	MAX	UNIT
Input Capacitance	Cin	-	6	pF
Input/Output Capacitance	CI/O	-	8	pF

Note :These parameters are guaranteed by device characterization, but not production tested.

AC TEST CONDITIONS

Input Pulse Levels	0.2V to Vcc - 0.2V
Input Rise and Fall Times	3ns
Input and Output Timing Reference Levels	1.5V
Output Load	$C_L = 50pF + 1TTL$, $I_{OH}/I_{OL} = -1mA/2mA$

AC ELECTRICAL CHARACTERISTICS

(1) READ CYCLE

PARAMETER	SYM.		AS6C6264-55		UNIT
			MIN.	MAX.	
Read Cycle Time	trc		55	-	ns
Address Access Time	taa		-	55	ns
Chip Enable Access Time	tace		-	55	ns
Output Enable Access Time	toe			30	ns
Chip Enable to Output in Low-Z	tcLz*		10	-	ns
Output Enable to Output in Low-Z	toLz*	ĺ	5	-	ns
Chip Disable to Output in High-Z	tcHZ*		-	20	ns
Output Disable to Output in High-Z	tonz*			20	ns
Output Hold from Address Change	tон		10	-	ns

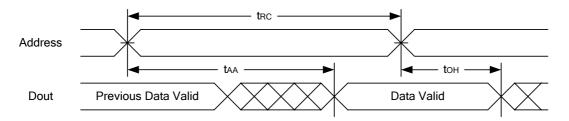
(2) WRITE CYCLE

PARAMETER	SYM.			AS6C6264-55			UNIT	
				MIN.	MAX.			1
Write Cycle Time	twc			55	-			ns
Address Valid to End of Write	taw		ĺ	50	-			ns
Chip Enable to End of Write	tcw			50	-			ns
Address Set-up Time	tas			0	-			ns
Write Pulse Width	twp		ĺ	45	-			ns
Write Recovery Time	twr			0	-			ns
Data to Write Time Overlap	tow			25	-			ns
Data Hold from End of Write Time	tон		ĺ	0	-			ns
Output Active from End of Write	tow*			5	-			ns
Write to Output in High-Z	twnz*			-	20			ns

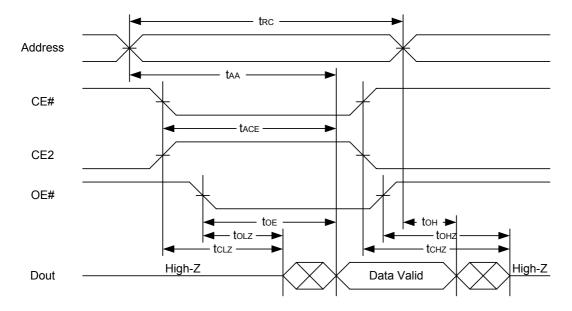
^{*}These parameters are guaranteed by device characterization, but not production tested.

TIMING WAVEFORMS

READ CYCLE 1 (Address Controlled) (1,2)



READ CYCLE 2 (CE# and CE2 and OE# Controlled) (1,3,4,5)

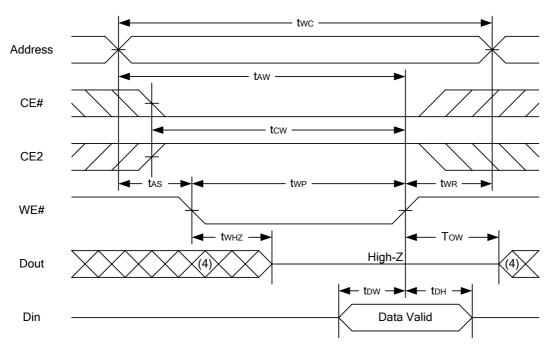


Notes:

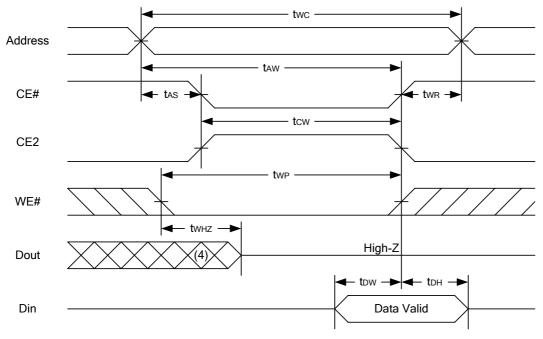
- 1.WE# is high for read cycle.
- 2.Device is continuously selected OE# = low, CE# = low., CE2 = high.
- 3.Address must be valid prior to or coincident with CE# = low, CE2 = high; otherwise tAA is the limiting parameter.
- 4.tclz, tolz, tchz and tohz are specified with CL = 5pF. Transition is measured ±500mV from steady state.
- 5.At any given temperature and voltage condition, t_{CHZ} is less than t_{CLZ}, t_{OHZ} is less than t_{OLZ}.



WRITE CYCLE 1 (WE# Controlled) (1,2,3,5,6)



WRITE CYCLE 2 (CE# and CE2 Controlled) (1,2,5,6)



Notes:

- 1.WE#, CE# must be high or CE2 must be low during all address transitions.
- 2.A write occurs during the overlap of a low CE#, high CE2, low WE#.
- 3.During a WE#controlled write cycle with OE# low, twp must be greater than twHz + tow to allow the drivers to turn off and data to be placed on the bus.
- 4.During this period, I/O pins are in the output state, and input signals must not be applied.
- 5.If the CE#low transition and CE2 high transition occurs simultaneously with or after WE# low transition, the outputs remain in a high impedance state.
- 6.tow and twHZ are specified with C_L = 5pF. Transition is measured $\pm 500mV$ from steady state.



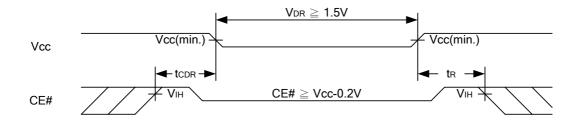
DATA RETENTION CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Vcc for Data Retention	1 1/00	CE# \geq Vcc - 0.2V or CE2 \leq 0.2V	1.5	-	5.5	V
Data Retention Current	Idr	V_{CC} = 1.5 V $CE\# \ge V_{CC}$ - 0.2 V or $CE2 \le 0.2V$	-	0.5	10	μA
Chip Disable to Data Retention Time	tcdr	See Data Retention Waveforms (below)	0	-	-	ns
Recovery Time	tr		t RC∗	-	-	ns

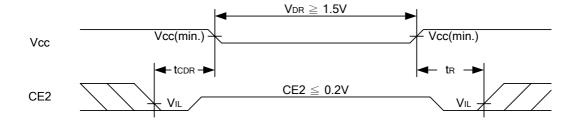
tRC∗ = Read Cycle Time

DATA RETENTION WAVEFORM

Low Vcc Data Retention Waveform (1) (CE# controlled)

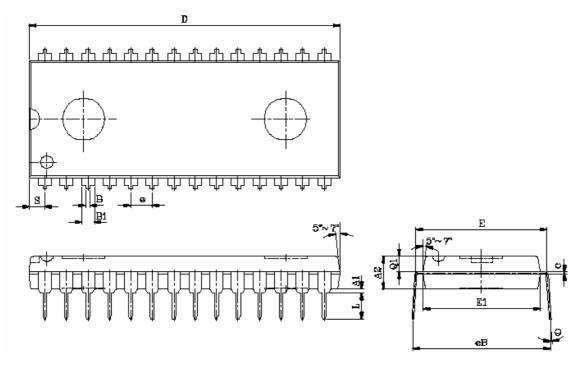


Low Vcc Data Retention Waveform (2) (CE2 controlled)

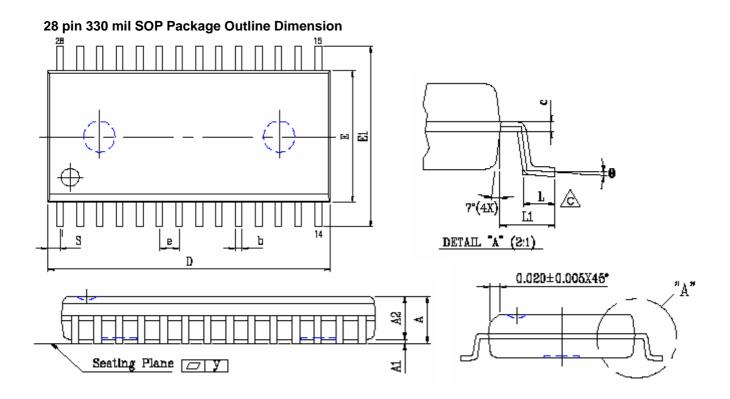


PACKAGE OUTLINE DIMENSION

28 pin 600 mil PDIP Package Outline Dimension

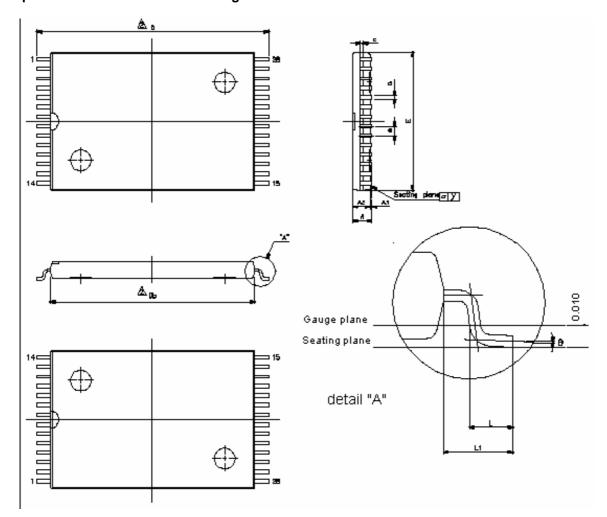


SYM. UNIT	INCH.(BASE)	MM(REF)
A1	0.010 (MIN)	0.254 (MIN)
A2	0.150±0.005	3.810±0.127
В	0.020 (MAX)	0.508(MAX)
B1	0.055 (MAX)	1.397(MAX)
С	0.012 (MAX)	0.304 (MAX)
D	1.430 (MAX)	36.322 (MAX)
Е	0.6 (TYP)	15.24 (TYP)
E1	0.52 (MAX)	13.208 (MAX)
е	0.100 (TYP)	2.540(TYP)
eB	0.625 (MAX)	15.87 (MAX)
L	0.180(MAX)	4.572(MAX)
S	0.06 (MAX)	1.524 (MAX)
Q1	0.08(MAX)	2.032(MAX)
Θ	15°(MAX)	15°(MAX)



SYM. UNIT	INCH(BASE)	MM(REF)
Α	0.120 (MAX)	3.048 (MAX)
A1	0.002(MIN)	0.05(MIN)
A2	0.098±0.005	2.489±0.127
b	0.016 (TYP)	0.406(TYP)
С	0.010 (TYP)	0.254(TYP)
D	0.728 (MAX)	18.491 (MAX)
Е	0.340 (MAX)	8.636 (MAX)
E1	0.465±0.012	11.811±0.305
е	0.050 (TYP)	1.270(TYP)
L	0.05 (MAX)	1.270 (MAX)
L1	0.067±0.008	1.702 ±0.203
S	0.047 (MAX)	1.194 (MAX)
у	0.003(MAX)	0.076(MAX)
Θ	0°~10°	0°~10°

28 pin 8mm x 13.4mm sTSOP Package Outline Dimension



SYM. UNIT	INCH(BASE)	MM(REF)	
Α	0.047 (MAX)	1.20 (MAX)	
A1	0.004±0.002	0.10±0.05	
A2	0.039±0.002	1.00±0.05	
b	0.006 (TYP)	0.15(TYP)	
С	0.010 (TYP)	0.254(TYP)	
Db	0.465±0.004	11.80±0.10	
E	0.315±0.004	8.00±0.10	
е	0.022 (TYP)	0.55(TYP)	
D	0.528±0.008	13.40±0.20	
L	0.020±0.004	0.50±0.10	
L1	0.0315±0.004	0.80±0.10	
у	0.08(MAX) 0.003(MAX)		
Θ	Θ $0^{\circ}\sim5^{\circ}$ $0^{\circ}\sim5^{\circ}$		

Note: E dimension is not including end flash. The total of both sides' end flash is not above 0.3mm.



ORDERING INFORMATION

Ordering Codes

				Operating	Speed
Alliance	Organization	VCC range	Package	Temp	ns
				Commercial ~	
AS6C6264-55PCN	8k x 8	2.7-5.5V	28pin 600mil PDIP	0° C to 70° C	55
AS6C6264-55PIN	8k x 8	2.7-5.5V	28pin 600mil PDIP	Industrial ~ -40°C to 85° C	55
AS6C6264-55SCN	8k x 8	2.7-5.5V	28pin 330mil SOP	Commercial ~ 0° C to 70° C	55
AS6C6264-55SIN	8k x 8	2.7-5.5V	28pin 330mil SOP	Industrial ~ -40°C to 85° C	55
AS6C6264-55STCN	8k x 8	2.7-5.5V	28pin sTSOP (8 x 13.4 mm)	Commercial ~ 0° C to 70° C	55
AS6C6264-55STIN	8k x 8	2.7-5.5V	28pin sTSOP (8 x 13.4 mm)	Industrial ~ -40°C to 85° C	55

Part numbering system

AS6C	6264	- 55	X	X	N
		Access Time	Package Options: P = 28 pin 600 mil P-DIP S = 28 pin 330 mil SOP ST = 28 pin sTSOP (8mm x 13.4 mm)	Temperature Range: C = Commercial (0°C to +70° C) I = Industrial (-40° to +85° C)	N = Lead Free ROHS Compliant Part





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Part Number: AS6C6264

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